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Kind regards,

Team Nexperia

INTEGRATED CIRCUITS

DATA SHEET

For a complete data sheet, please also download:

- The IC06 74HC/HCT/HCU/HCMOS Logic Family Specifications
- The IC06 74HC/HCT/HCU/HCMOS Logic Package Information
- The IC06 74HC/HCT/HCU/HCMOS Logic Package Outlines

74HC/HCT9114

Nine wide Schmitt trigger buffer; open drain outputs; inverting

Product specification Supersedes data of March 1988 File under Integrated Circuits, IC06 December 1990





74HC/HCT9114

FEATURES

- Schmitt trigger action on all data inputs
- Output capability: standard (open drain)
- I_{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT9114 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT9114 are nine wide Schmitt trigger inverting buffer with open drain outputs and Schmitt trigger inputs.

The Schmitt trigger action in the data inputs transform slowly changing input signals into sharply defined jitter-free output signals.

The 74HC/HCT9114 have open-drain N-transistor outputs, which are not clamped by a diode connected to V_{CC}. In the OFF-state, i.e. when one input is LOW, the output may be pulled to any voltage between GND and V_{Omax}. This allows the device to be used as a LOW-to-HIGH or HIGH-to-LOW level shifter. For digital operation and OR-tied output applications, these devices must have a pull-up resistor to establish a logic HIGH level.

The "9114" is identical to the "9115" but has inverting outputs.

QUICK REFERENCE DATA

 $GND = 0 V; T_{amb} = 25 °C; t_r = t_f = 6 ns$

SYMBOL	PARAMETER	CONDITIONS	TYP	UNIT		
STWIBOL	PARAMETER	CONDITIONS	НС	нст	UNIT	
t _{PHL} / t _{PLZ}	propagation delay A_n to \overline{Y}_n	C _L = 15 pF; V _{CC} = 5 V	12	13	ns	
C _I	input capacitance		3.5	3.5	pF	
C _{PD}	power dissipation capacitance per buffer	notes 1 and 2	5	5	pF	

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$$
 where:

f_i = input frequency in MHz

f_o = output frequency in MHz

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs}$

C_L = output load capacitance in pF

V_{CC} = supply voltage in V

- 2. For HC the condition is $V_I = GND$ to V_{CC}
 - For HCT the condition is $V_I = GND$ to $V_{CC} 1.5 \text{ V}$

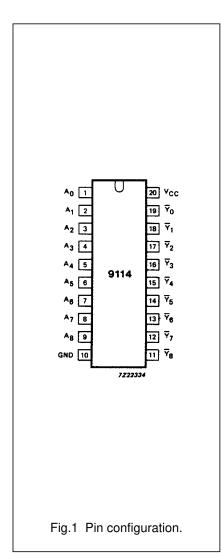
ORDERING INFORMATION

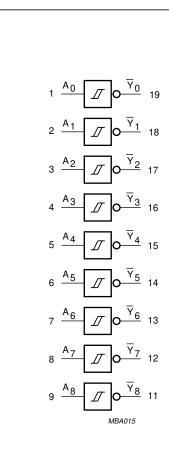
See "74HC/HCT/HCU/HCMOS Logic Package Information".

74HC/HCT9114

PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1, 2, 3, 4, 5, 6, 7, 8, 9	A ₀ to A ₈	data inputs
10	GND	ground (0 V)
19, 18, 17, 16, 15, 14, 13, 12, 11	\overline{Y}_0 to \overline{Y}_8	data outputs
20	V _{CC}	positive supply voltage





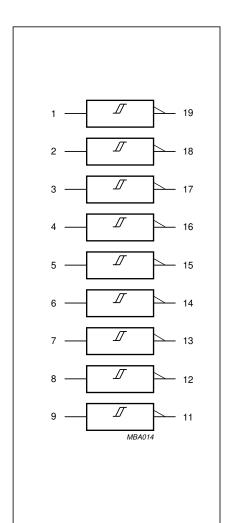


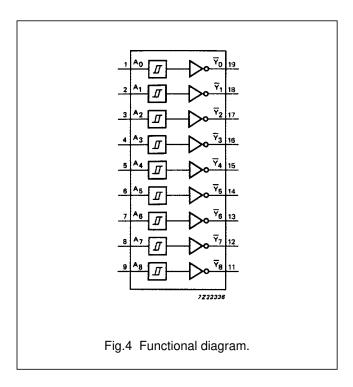
Fig.2 Logic diagram.

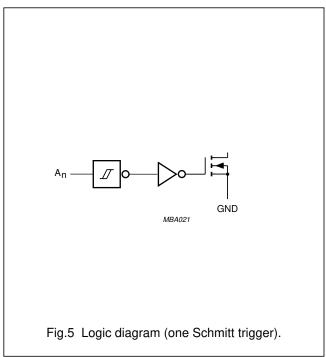
Fig.3 IEC logic diagram.

Philips Semiconductors Product specification

Nine wide Schmitt trigger buffer; open drain outputs; inverting

74HC/HCT9114





FUNCTION TABLE

INPUTS	OUTPUTS					
A _n	\overline{Y}_{n}					
L	Z					
Н	L					

Notes

- 1. H = HIGH voltage level
 - L = LOW voltage level
 - Z = high impedance OFF-state

74HC/HCT9114

DC CHARACTERISTICS FOR 74HC

For the DC characteristics see "74HC/HCT/HCU/HCMOS Logic Family Specifications". Transfer characteristics are given below.

Output capability: standard

I_{CC} category: MSI

TRANSFER CHARACTERISTICS FOR 74HC

Voltages are referred to GND (ground = 0 V)

SYMBOL		T _{amb} (°C)								TEST CONDITIONS		
	PARAMETER				74H	С			UNIT			
	PARAMETER		+25		-40 t	o +85	-40 to	+125	UNIT	V _{CC}	WAVEFORMS	
		min.	typ.	max.	min.	max.	min.	max.		(-)		
V _{T+}	positive-going threshold	0.70 1.75 2.30	1.13 2.37 3.11	1.50 3.15 4.20	0.70 1.75 2.30	1.50 3.15 4.20	0.70 1.75 2.30	1.50 3.15 4.20	V	2.0 4.5 6.0	Fig.6	
V _{T-}	negative-going threshold	0.30 1.35 1.80	0.70 1.80 2.43	1.10 2.40 3.30	0.30 1.35 1.80	1.10 2.40 3.30	0.30 1.35 1.80	1.10 2.40 3.30	V	2.0 4.5 6.0	Fig.6	
V _H	hysteresis ($V_{T+} - V_{T-)}$	0.2 0.4 0.5	0.43 0.57 0.68	0.80 1.00 1.10	0.18 0.40 0.50	0.80 1.00 1.10	0.15 0.40 0.50	0.80 1.00 1.10	V	2.0 4.5 6.0	Fig.6	

AC CHARACTERISTICS FOR 74HC

 $GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF$

SYMBOL					T _{amb} (°		TEST CONDITIONS				
	PARAMETER				74HC	;			UNIT		
STWIBOL	PANAMETEN		+25		−40 t	o +85	−40 to	+125	UNIT	V _{CC}	WAVEFORMS
		min.	typ.	max.	min.	max.	min.	max.		,	
t _{PHL} / t _{PLZ}	propagation delay		36	110		140		165	ns	2.0	Fig.7
	A_n to \overline{Y} n		13	22		28		33		4.5	
			10	19		24		28		6.0	
t _{THL}	output transition time		19	75		95		110	ns	2.0	Fig.7
			7	15		19		22		4.5	
			6	13		16		19		6.0	

74HC/HCT9114

DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see "74HC/HCT/HCU/HCMOS Logic Family Specifications". Transfer characteristics are given below.

Output capability: standard

I_{CC} category: MSI

Note to HCT types

The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given in the family specifications.

To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
An	0.3

TRANSFER CHARACTERISTICS FOR 74HCT

Voltages are referred to GND (ground = 0 V)

					T _{amb} (°		TEST CONDITIONS				
SYMBOL	PARAMETER				74HC	Т			UNIT		
STINIBOL	FARAWLILR	+25			−40 to +85		-40 to +125		ONIT	V _{CC} (V)	WAVEFORMS
		min.	typ.	max.	min.	max.	min.	max.		,	
V_{T_+}	positive-going threshold	0.9 1.2	1.50 1.70	2.0 2.1	0.9 1.2	2.0 2.1	0.9 1.2	2.0 2.1	٧	4.5 5.5	Fig.6
V _{T-}	negative-going threshold	0.7 0.8	1.06 1.27	1.4 1.7	0.7 0.8	1.4 1.7	0.7 0.8	1.4 2.7	V	4.5 5.5	Fig.6
V _H	hysteresis (V _{T+} – V _{T-})	0.2 0.2	0.44 0.44		0.2 0.2	0.8 0.8	0.2 0.2	0.8 0.8	V	4.5 5.5	Fig.6

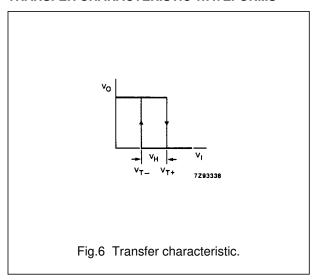
AC CHARACTERISTICS FOR 74HCT

 $GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF$

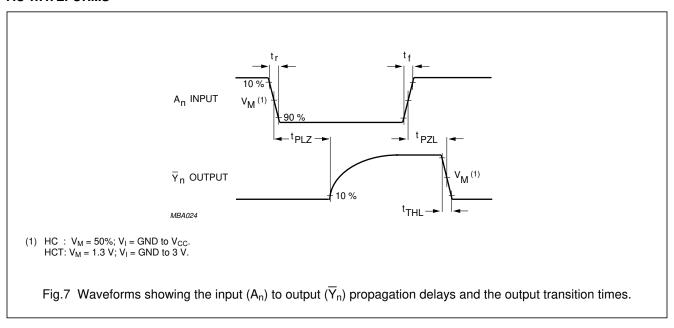
SYMBOL	PARAMETER				T _{amb} (UNIT	TEST CONDITIONS				
					74H0						
STWBOL	FARAWLILA	+25			-40 to +85		−40 to +125		ONIT	V _{CC} (V)	WAVEFORMS
		min.	typ.	max.	min.	max.	min.	max.		``	
t _{PHL} / t _{PLZ}	$\begin{array}{c} \text{propagation delay} \\ A_n \text{ to } \overline{Y}_n \end{array}$		17	31		39		47	ns	4.5	Fig.7
t _{THL}	output transition time		7	15		19		22	ns	4.5	Fig.7

74HC/HCT9114

TRANSFER CHARACTERISTIC WAVEFORMS



AC WAVEFORMS



PACKAGE OUTLINES

See "74HC/HCT/HCU/HCMOS Logic Package Outlines".